

# SANYO Semiconductors DATA SHEET

# 2SK3944 — General-Purpose Switching Device Applications

#### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.

# **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		2	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	8	Α
Allowable Power Dissipation	Do	Mounted on a ceramic board (250mm <sup>2</sup> X0.8mm)	1	W
	PD	Tc=25°C	3.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	60			V
Zero-Gate Voltage Drain Current	IDSS	VDS=60V, VGS=0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =1A	0.75	1.5		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =1A, V <sub>G</sub> S=10V		260	340	mΩ
	RDS(on)2	ID=1A, VGS=4V		340	480	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		150		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		19		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		13		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		7		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		3.7		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		19.5		ns
Fall Time	tf	See specified Test Circuit.		12.5		ns

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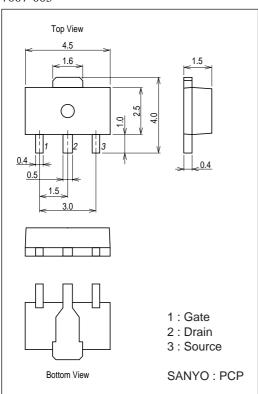
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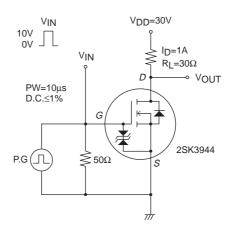
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	] Offic
Total Gate Charge	Qg	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A		4.8		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A		1.0		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A		1.0		nC
Diode Forward Voltage	VSD	IS=2A, VGS=0V		0.93	1.2	V

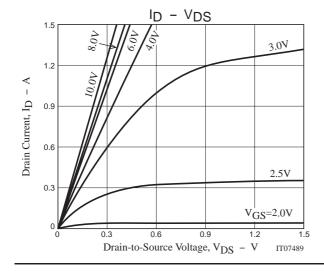
# **Package Dimensions**

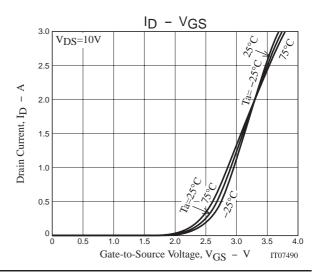
unit : mm 7007-003

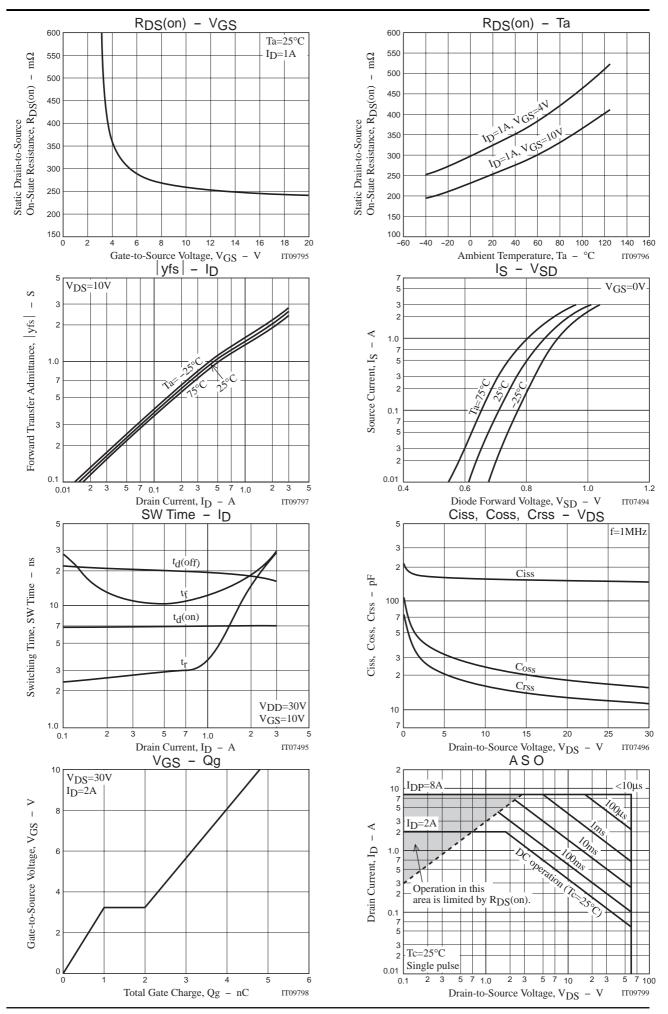


# **Switching Time Test Circuit**

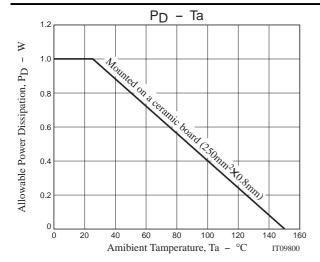


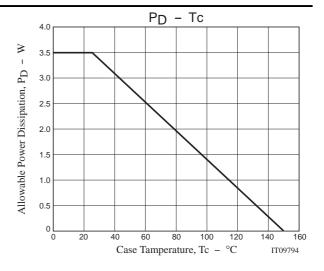






#### 2SK3944





Note on usage: Since the 2SK3944 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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